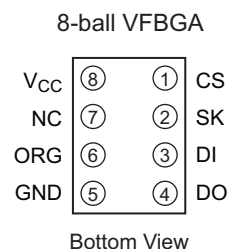
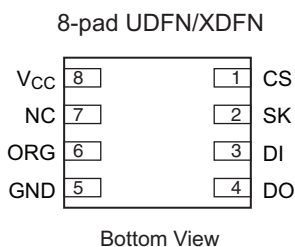
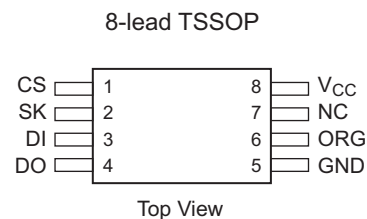
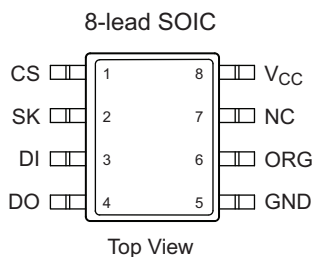


1. Pin Configurations and Pinouts

Table 1-1. Pin Configurations

Pin Name	Function
CS	Chip Select
SK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
V _{CC}	Power Supply
ORG	Internal Organization
NC	No Connect



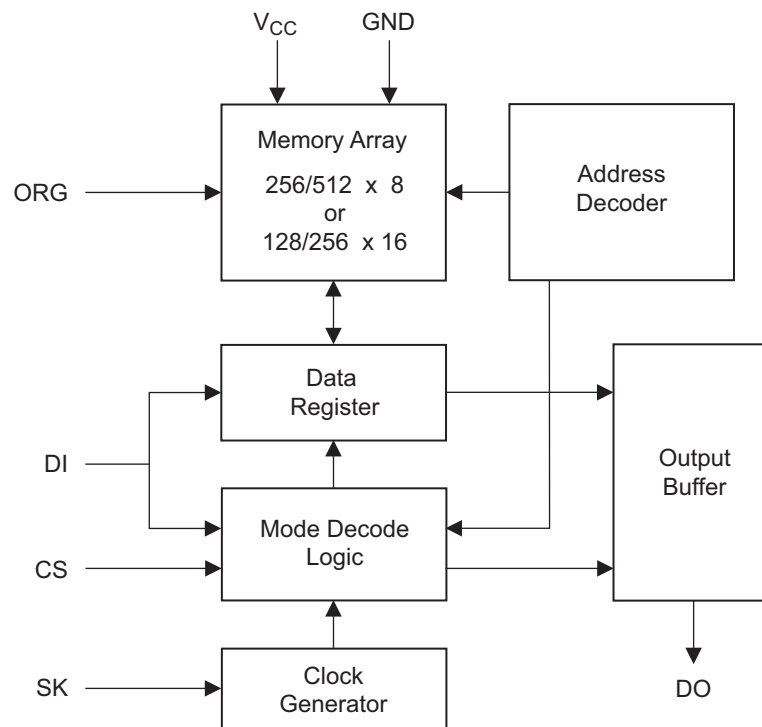
Note: Drawings are not to scale.

2. Absolute Maximum Ratings*

Operating Temperature	–55°C to +125°C
Storage Temperature	–65°C to +150°C
Voltage on any pin with respect to ground	–1.0V to +7.0V
Maximum Operating Voltage	6.25V
DC Output Current50mA

*Notice: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

3. Block Diagram



Note: When the ORG pin is connected to V_{CC} , the x16 organization is selected. When it is connected to ground, the x8 organization is selected. If the ORG pin is left unconnected, and the application does not load the input beyond the capability of the internal $1M\Omega$ pull-up resistor, then the x16 organization is selected.

4. Memory Organization

4.1 Pin Capacitance⁽¹⁾

Applicable over recommended operating range from $T_A = 25^\circ\text{C}$, $f = 1.0\text{MHz}$, $V_{CC} = 5.0\text{V}$ (unless otherwise noted).

Symbol	Test Conditions	Max	Units	Conditions
C_{OUT}	Output Capacitance (DO)	5	pF	$V_{OUT} = 0\text{V}$
C_{IN}	Input Capacitance (CS, SK, DI)	5	pF	$V_{IN} = 0\text{V}$

Note: 1. This parameter is characterized, and is not 100% tested.

4.2 DC Characteristics

Applicable over recommended operating range from $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$, $V_{CC} = 1.7\text{V}$ to 5.5V (unless otherwise noted).

Symbol	Parameter	Test Condition	Min	Typ	Max	Unit
V_{CC1}	Supply Voltage		1.7		5.5	V
V_{CC2}	Supply Voltage		2.5		5.5	V
V_{CC3}	Supply Voltage		4.5		5.5	V
I_{CC}	Supply Current	$V_{CC} = 5.0\text{V}$	Read at 1.0MHz	0.5	2.0	mA
			Write at 1.0MHz	0.5	2.0	mA
I_{SB1}	Standby Current	$V_{CC} = 1.7\text{V}$	CS = 0V	0.4	1.0	μA
I_{SB2}	Standby Current	$V_{CC} = 2.5\text{V}$	CS = 0V	6.0	10.0	μA
I_{SB3}	Standby Current	$V_{CC} = 5.0\text{V}$	CS = 0V	10.0	15.0	μA
I_{IL}	Input Leakage	$V_{IN} = 0\text{V}$ to V_{CC}		0.1	3.0	μA
I_{OL}	Output Leakage	$V_{IN} = 0\text{V}$ to V_{CC}		0.1	3.0	μA
$V_{IL1}^{(1)}$	Input Low Voltage	$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	-0.6		0.8	V
$V_{IH1}^{(1)}$	Input High Voltage	$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	2.0		$V_{CC} + 1$	V
$V_{IL2}^{(1)}$	Input Low Voltage	$1.7\text{V} \leq V_{CC} \leq 2.5\text{V}$	-0.6		$V_{CC} \times 0.3$	V
$V_{IH2}^{(1)}$	Input High Voltage	$1.7\text{V} \leq V_{CC} \leq 2.5\text{V}$	$V_{CC} \times 0.7$		$V_{CC} + 1$	V
V_{OL1}	Output Low Voltage	$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	$I_{OL} = 2.1\text{mA}$		0.4	V
V_{OH1}	Output High Voltage	$2.5\text{V} \leq V_{CC} \leq 5.5\text{V}$	$I_{OH} = -0.4\text{mA}$	2.4		V
V_{OL2}	Output Low Voltage	$1.7\text{V} \leq V_{CC} \leq 2.5\text{V}$	$I_{OL} = 0.15\text{mA}$		0.2	V
V_{OH2}	Output High Voltage	$1.7\text{V} \leq V_{CC} \leq 2.5\text{V}$	$I_{OH} = -100\mu\text{A}$	$V_{CC} - 0.2$		V

Note: 1. V_{IL} min and V_{IH} max are reference only, and are not tested.

4.3 AC Characteristics

Applicable over recommended operating range from $T_{AI} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} =$ as specified, $C_L = 1$ TTL gate and 100pF (unless otherwise noted).

Symbol	Parameter	Test Condition	Min	Max	Units
f_{SK}	SK Clock Frequency	$4.5V \leq V_{CC} \leq 5.5V$	0	2	MHz
		$2.5V \leq V_{CC} \leq 5.5V$	0	1	MHz
		$1.7V \leq V_{CC} \leq 5.5V$	0	250	kHz
t_{SKH}	SK High Time	$2.5V \leq V_{CC} \leq 5.5V$	250		ns
		$1.7V \leq V_{CC} \leq 5.5V$	1000		ns
t_{SKL}	SK Low Time	$2.5V \leq V_{CC} \leq 5.5V$	250		ns
		$1.7V \leq V_{CC} \leq 5.5V$	1000		ns
t_{CS}	Minimum CS Low Time	$2.5V \leq V_{CC} \leq 5.5V$	250		ns
		$1.7V \leq V_{CC} \leq 5.5V$	1000		ns
t_{CSS}	CS Setup Time	Relative to SK			
		$2.5V \leq V_{CC} \leq 5.5V$	50		ns
		$1.7V \leq V_{CC} \leq 5.5V$	200		ns
t_{DIS}	DI Setup Time	Relative to SK			
		$2.5V \leq V_{CC} \leq 5.5V$	100		ns
		$1.7V \leq V_{CC} \leq 5.5V$	400		ns
t_{CSH}	CS Hold Time	Relative to SK		0	ns
t_{DIH}	DI Hold Time	Relative to SK			
		$2.5V \leq V_{CC} \leq 5.5V$	100		ns
		$1.7V \leq V_{CC} \leq 5.5V$	400		ns
t_{PD1}	Output Delay to 1	AC Test			
		$2.5V \leq V_{CC} \leq 5.5V$		250	ns
		$1.7V \leq V_{CC} \leq 5.5V$		1000	ns
t_{PD0}	Output Delay to 0	AC Test			
		$2.5V \leq V_{CC} \leq 5.5V$		250	ns
		$1.7V \leq V_{CC} \leq 5.5V$		1000	ns
t_{SV}	CS to Status Valid	AC Test			
		$2.5V \leq V_{CC} \leq 5.5V$		250	ns
		$1.7V \leq V_{CC} \leq 5.5V$		1000	ns
t_{DF}	CS to DO in High-impedance	AC Test			
		$2.5V \leq V_{CC} \leq 5.5V$		150	ns
		CS = V_{IL}		400	ns
t_{WP}	Write Cycle Time	$1.7V \leq V_{CC} \leq 5.5V$		5	ms
Endurance ⁽¹⁾	5.0V, 25°C		1,000,000		Write Cycles

Note: 1. This parameter is characterized, and is not 100% tested.

5. Functional Description

The AT93C56B/66B is accessed via a simple and versatile 3-wire serial communication interface. Device operation is controlled by seven instructions issued by the Host processor. A valid instruction starts with a rising edge of CS and consists of a Start bit (Logic 1), followed by the appropriate opcode, and the desired memory address location.

Table 5-1. AT93C56B/66B Instruction Set

Instruction	SB	Opcode	Address		Data		Comments
			x8 ⁽¹⁾	x16 ⁽¹⁾	x8	x16	
READ	1	10	A ₈ – A ₀	A ₇ – A ₀			Reads data stored in memory at specified address.
EWEN	1	00	11XXXXXXX	11XXXXXXX			Write Enable must precede all programming modes.
ERASE	1	11	A ₈ – A ₀	A ₇ – A ₀			Erases memory location A _N – A ₀ .
WRITE	1	01	A ₈ – A ₀	A ₇ – A ₀	D ₇ – D ₀	D ₁₅ – D ₀	Writes memory location A _N – A ₀ .
ERAL	1	00	10XXXXXXX	10XXXXXXX			Erases all memory locations. Valid only at V _{CC3} (Section 4.2, “DC Characteristics” on page 4).
WRAL	1	00	01XXXXXXX	01XXXXXXX	D ₇ – D ₀	D ₁₅ – D ₀	Writes all memory locations. Valid only at V _{CC3} (Section 4.2) and Disable Register cleared.
EWDS	1	00	00XXXXXXX	00XXXXXXX			Disables all programming instructions.

Note: 1. The Xs in the address field represent don't care values, and must be clocked.

READ: The READ instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the Serial Output pin, DO. Output data changes are synchronized with the rising edges of the Serial Clock pin, SK. It should be noted that a dummy bit (Logic 0) precedes the 8-bit or 16-bit data output string. The AT93C56B/66B supports sequential Read operations. The device will automatically increment the internal address pointer and clock out the next memory location as long as Chip Select (CS) is held high. In this case, the dummy bit (Logic 0) will not be clocked out between memory locations, thus allowing for a continuous stream of data to be read.

Erase/Write Enable (EWEN): To ensure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out.

Note: Once in the EWEN state, programming remains enabled until an EWDS instruction is executed, or V_{CC} power is removed from the part.

ERASE: The ERASE instruction programs all bits in the specified memory location to the Logic 1 state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} . A Logic 1 at the DO pin indicates that the selected memory location has been erased, and the part is ready for another instruction.

WRITE: The WRITE instruction contains the 8-bits or 16-bits of data to be written into the specified memory location. The self-timed programming cycle, t_{WP} , starts after the last bit of data is received at Serial Data Input pin DI. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} . A

Logic 0 at DO indicates that programming is still in progress. A Logic 1 indicates that the memory location at the specified address has been written with the data pattern contained in the instruction, and the part is ready for further instructions. A Ready/Busy status cannot be obtained if CS is brought high after the end of the self-timed programming cycle, t_{WP} .

Erase All (ERAL): The Erase All (ERAL) instruction programs every bit in the Memory Array to the Logic 1 state and is primarily used for testing purposes. The DO pin outputs the ready/busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} . The ERAL instruction is valid only at V_{CC3} ([Section 4.2, “DC Characteristics” on page 4](#)).

Write All (WRAL): The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} . The WRAL instruction is valid only at V_{CC3} ([Section 4.2](#)).

Erase/Write Disable (EWDS): To protect against accidental data disturbance, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the Read instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

6. Timing Diagrams

Figure 6-1. Synchronous Data Timing

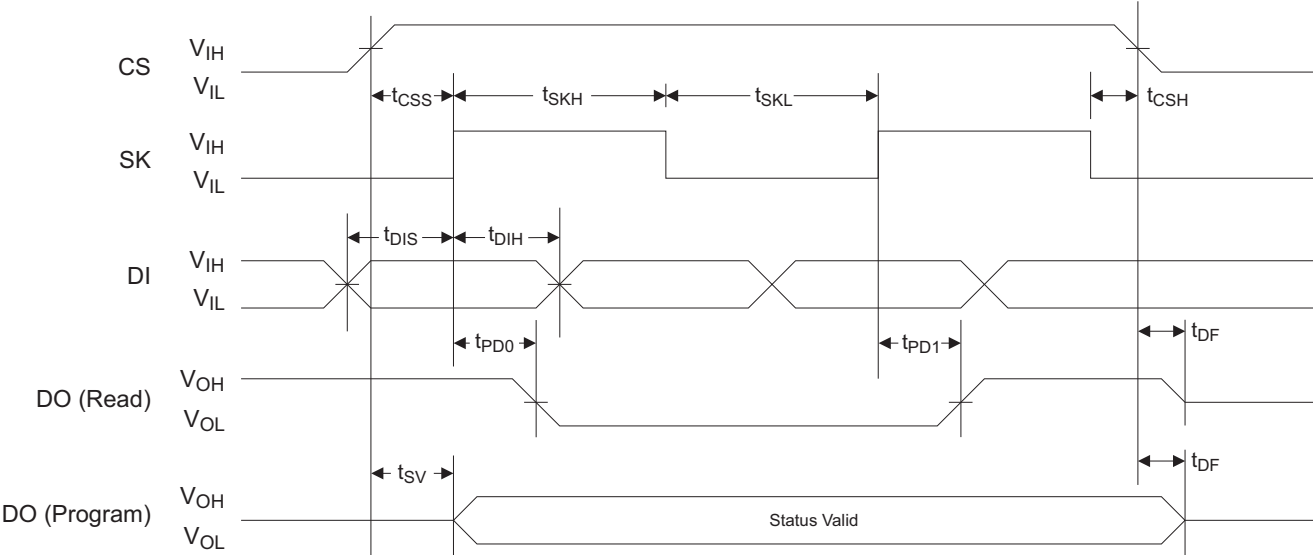


Table 6-1. Organization Key for Timing Diagrams

I/O	AT93C56B (2K)		AT93C66B (4K)	
	x8	x16	x8	x16
A _N	A ₈ ⁽¹⁾	A ₇ ⁽²⁾	A ₈	A ₇
D _N	D ₇	D ₁₅	D ₇	D ₁₅

Notes: 1. A₈ is a don't-care value, but the extra clock is required.
2. A₇ is a don't-care value, but the extra clock is required.

Figure 6-2. READ Timing

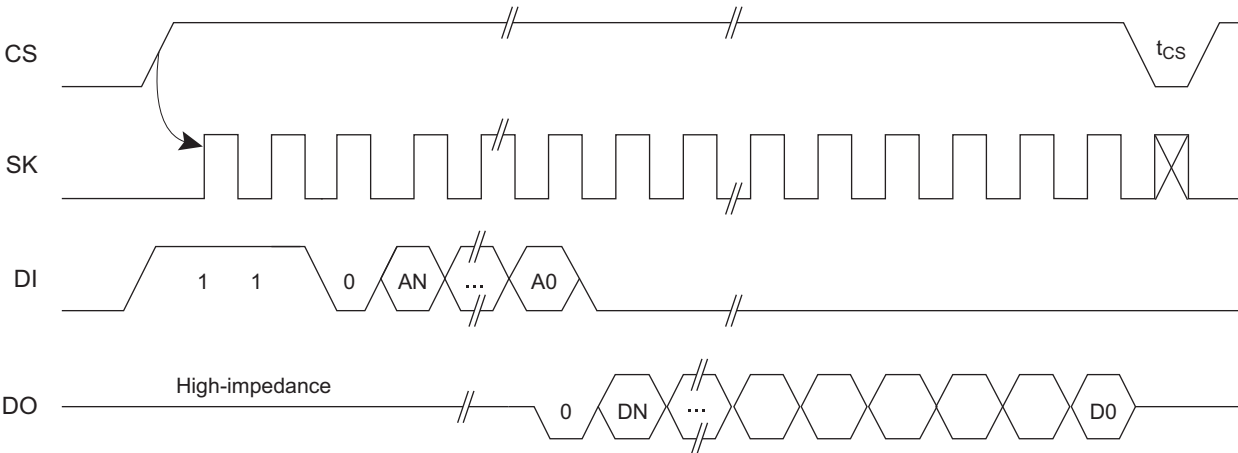


Figure 6-3. EWEN Timing

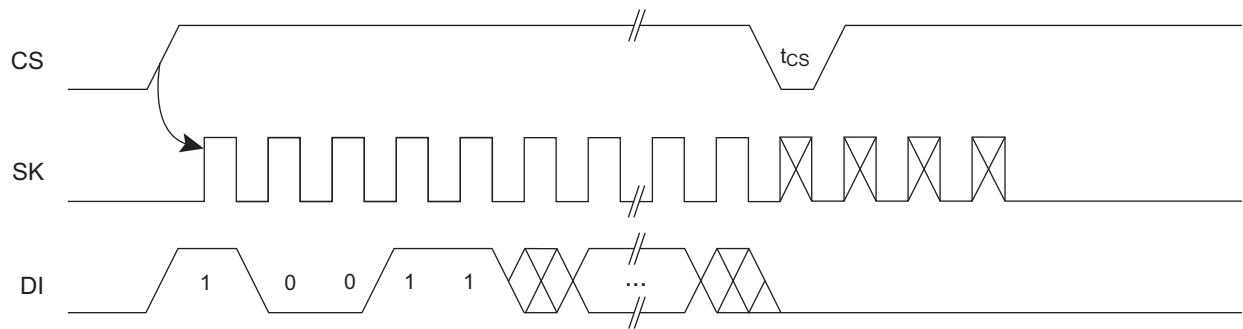


Figure 6-4. ERASE Timing

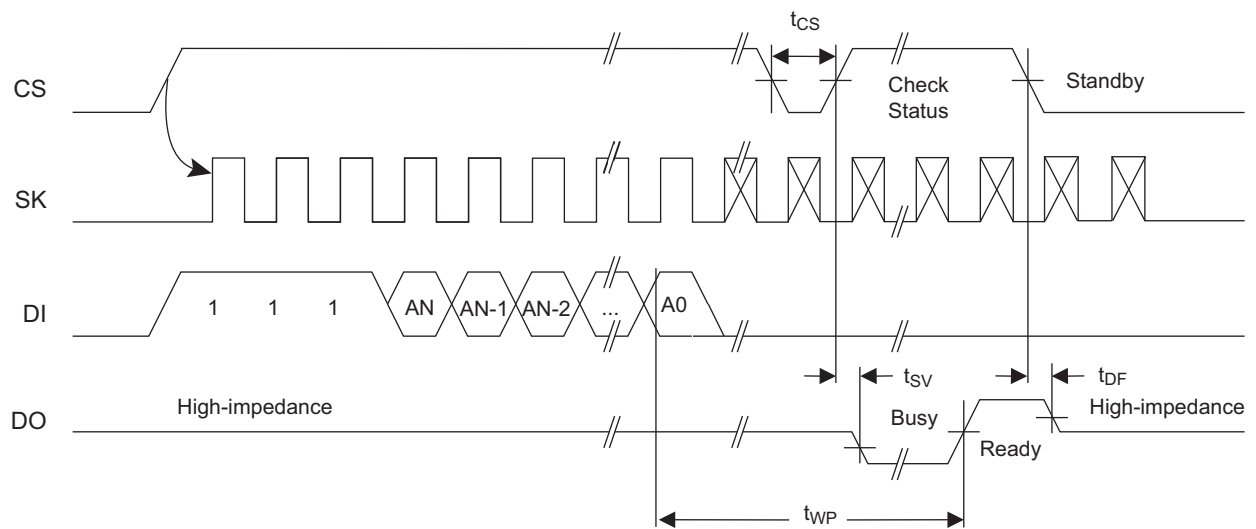


Figure 6-5. WRITE Timing

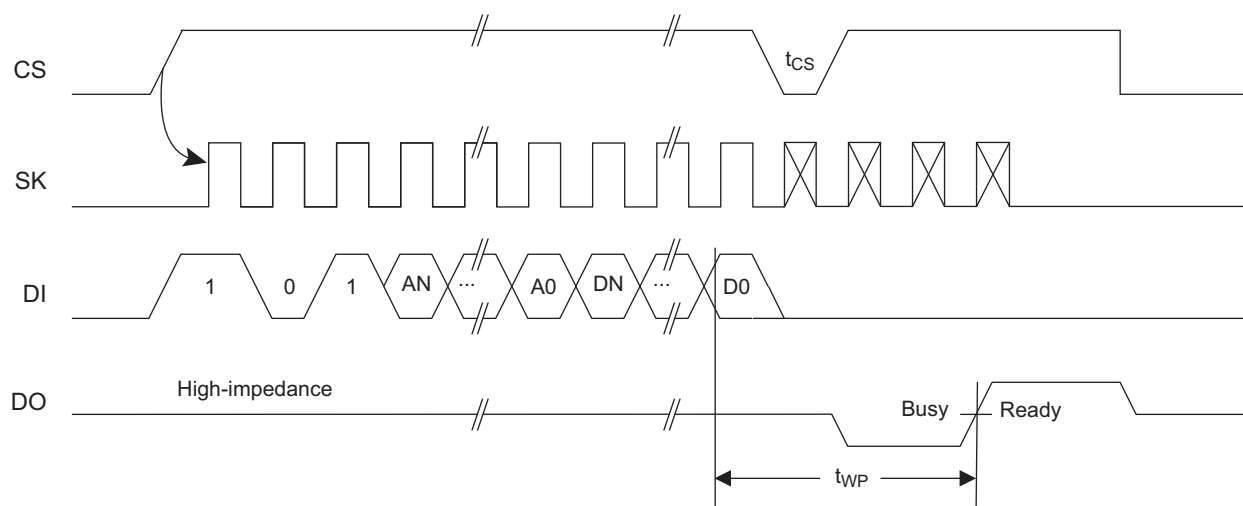
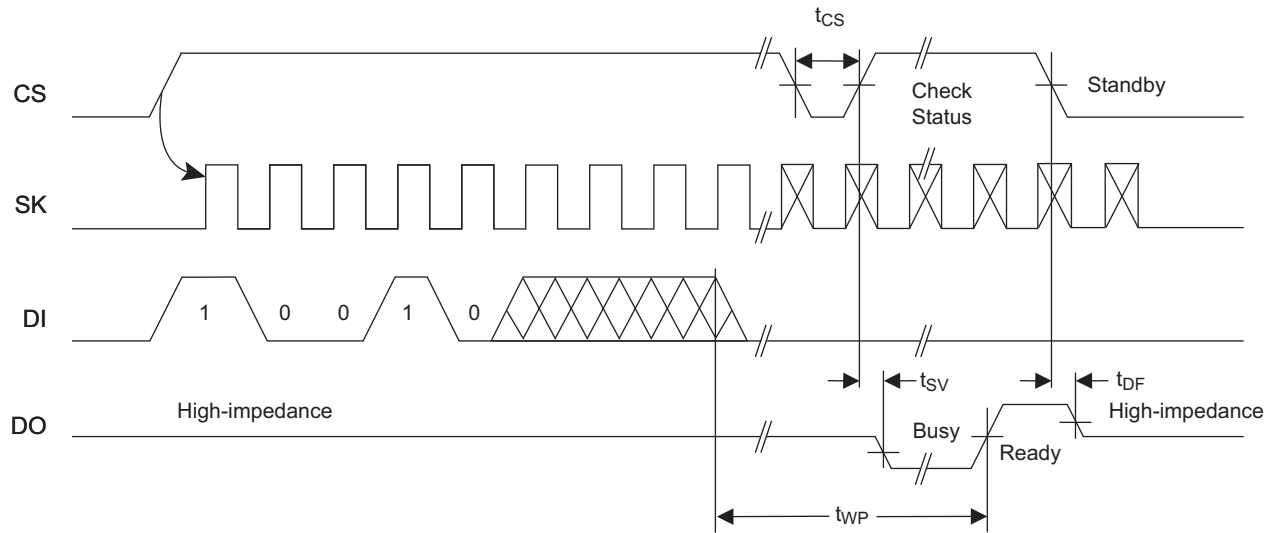
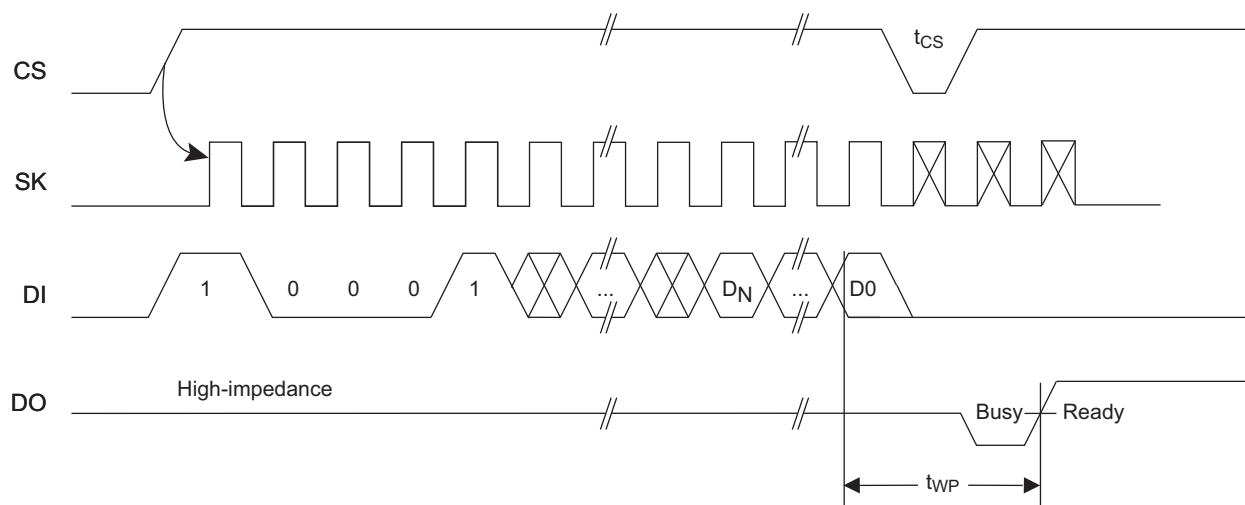


Figure 6-6. ERAL Timing⁽¹⁾



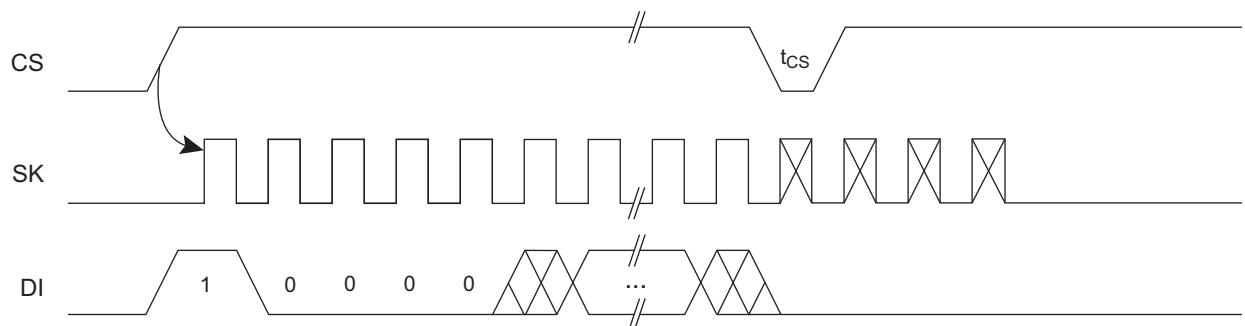
Note: 1. Valid only at V_{CC3} (Section 4.2).

Figure 6-7. WRAL Timing⁽¹⁾

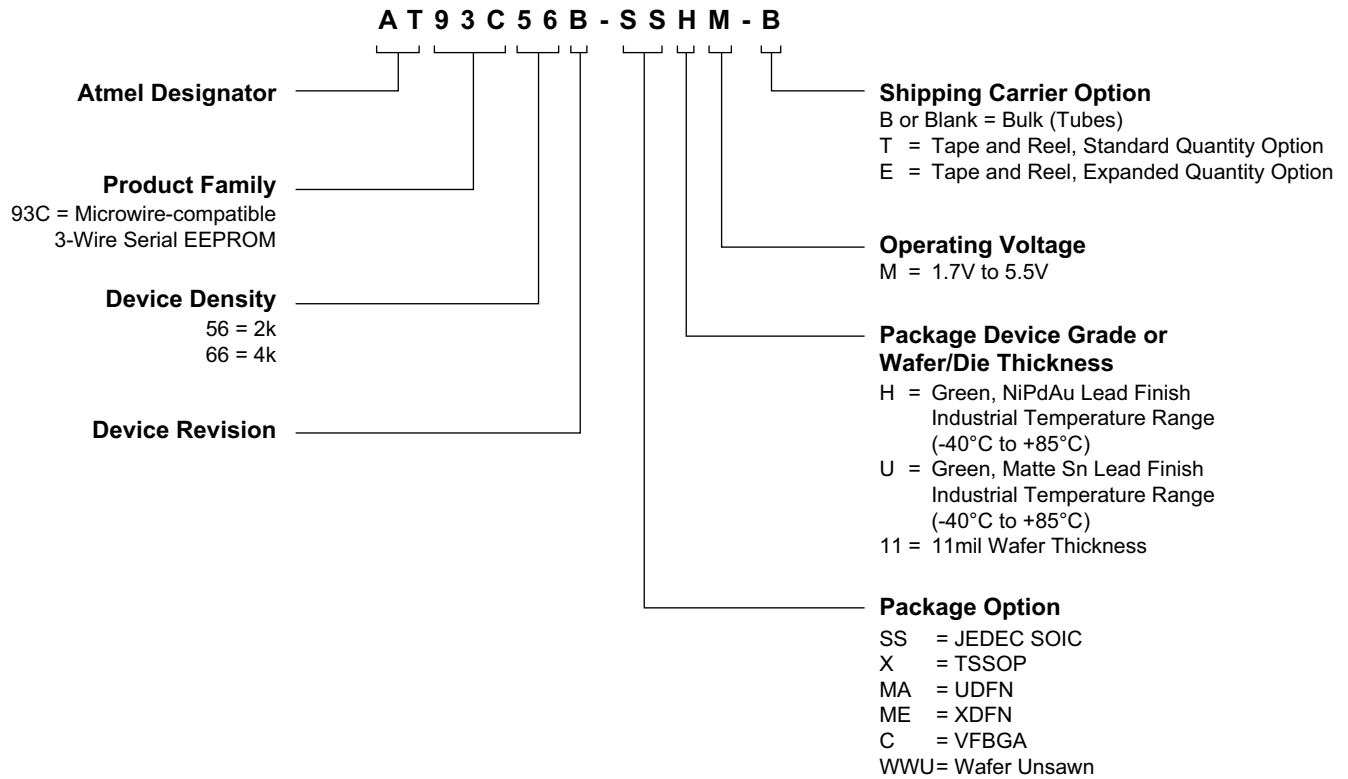


Note: 1. Valid only at V_{CC3} (Section 4.2).

Figure 6-8. EWDS Timing



7. Ordering Code Detail



8. Ordering Information

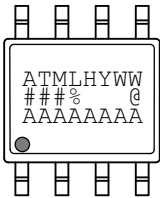
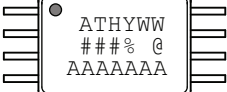



Atmel Ordering Code	Lead Finish	Package	Delivery Information		Operation Range
			Form	Quantity	
AT93C56B-SSH-M-B	NiPdAu (Lead-free/Halogen-free)	8S1	Bulk (Tubes)	100 per Tube	Industrial Temperature (-40°C to 85°C)
AT93C56B-SSH-M-T			Tape and Reel	4,000 per Reel	
AT93C56B-XHM-B		8X	Bulk (Tubes)	100 per Tube	
AT93C56B-XHM-T			Tape and Reel	5,000 per Reel	
AT93C56B-MAHM-T		8MA2	Tape and Reel	5,000 per Reel	
AT93C56B-MAHM-E			Tape and Reel	15,000 per Reel	
AT93C56B-MEHM-T		8ME1	Tape and Reel	5,000 per Reel	
AT93C56B-CUM-T	SnAgCu (Lead-free/Halogen-free)	8U3-1	Tape and Reel	5,000 per Reel	
AT93C56B-WWU11M ⁽¹⁾	N/A	Wafer Sale	Note 1		
AT93C66B-SSH-M-B	NiPdAu (Lead-free/Halogen-free)	8S1	Bulk (Tubes)	100 per Tube	Industrial Temperature (-40°C to 85°C)
AT93C66B-SSH-M-T			Tape and Reel	4,000 per Reel	
AT93C66B-XHM-B		8X	Bulk (Tubes)	100 per Tube	
AT93C66B-XHM-T			Tape and Reel	5,000 per Reel	
AT93C66B-MAHM-T		8MA2	Tape and Reel	5,000 per Reel	
AT93C66B-MAHM-E			Tape and Reel	15,000 per Reel	
AT93C66B-MEHM-T		8ME1	Tape and Reel	5,000 per Reel	
AT93C66B-CUM-T	SnAgCu (Lead-free/Halogen-free)	8U3-1	Tape and Reel	5,000 per Reel	
AT93C66B-WWU11M ⁽¹⁾	N/A	Wafer Sale	Note 1		

Note: 1. For wafer sales, please contact Atmel sales.

Package Type	
8S1	8-lead, 0.150" wide, Plastic Gull Wing, Small Outline (JEDEC SOIC)
8X	8-lead, 0.170" wide, Thin Shrink Small Outline (TSSOP)
8MA2	8-pad, 2.00mm x 3.00mm body, 0.50mm pitch, Ultra Thin Dual No Lead (UDFN)
8ME1	8-pad, 1.80mm x 2.20mm body, Extra Thin Dual No Lead (XDFN)
8U3-1	8-ball, 1.50mm x 2.00mm body, 0.50mm pitch, Small Die Ball Grid Array (VFBGA)

9. Part Markings

AT93C56B and AT93C66B: Package Marking Information


8-lead SOIC 	8-lead TSSOP 	8-pad UDFN 2.0 x 3.0 mm Body 
8-pad XDFN 1.8 x 2.2 mm Body 	8-ball VFBGA 1.5 x 2.0 mm Body 	

Note 1: ● designates pin 1

Note 2: Package drawings are not to scale

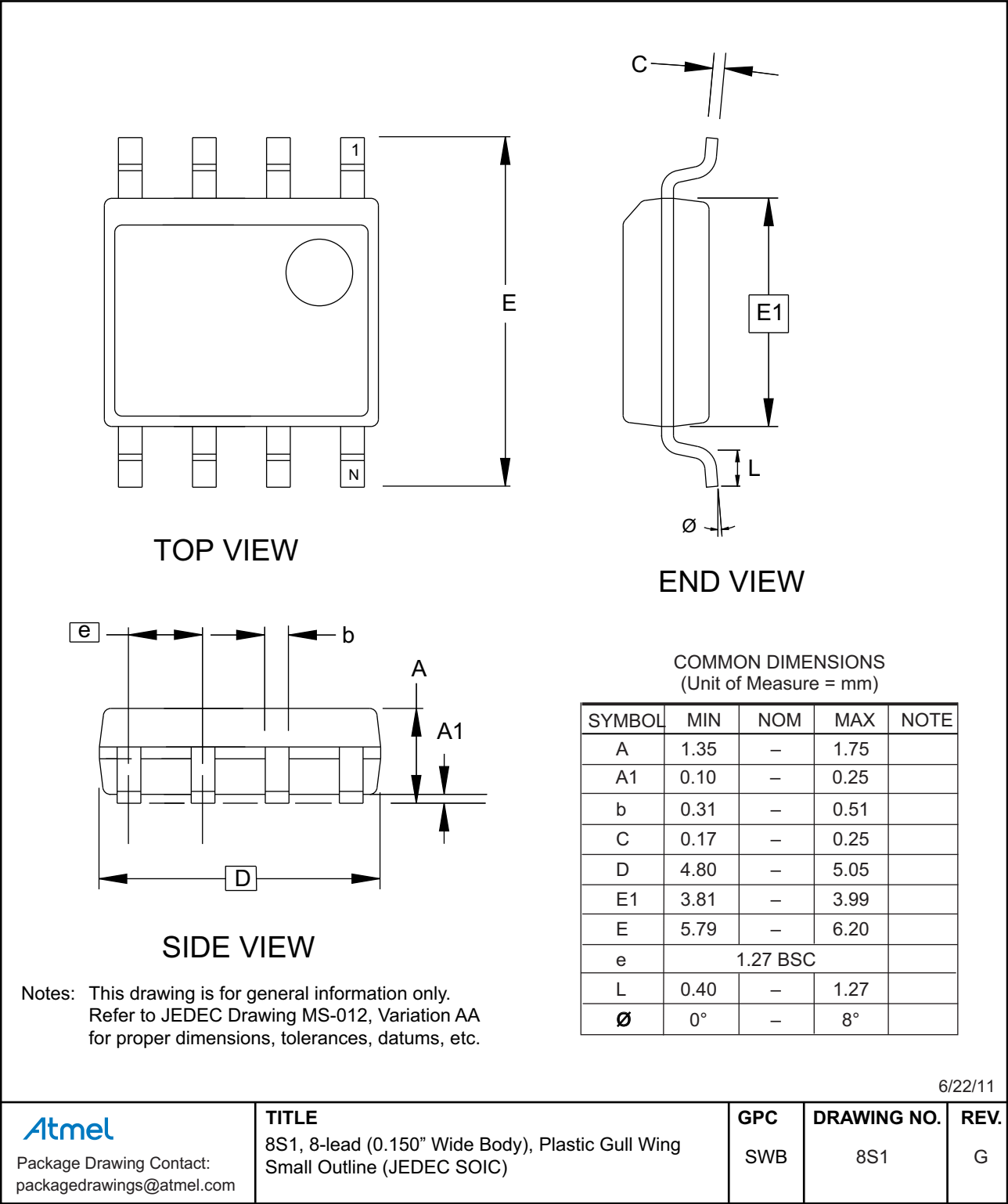
Catalog Number Truncation			
AT93C56B		Truncation Code ###: 56B	
AT93C66B		Truncation Code ###: 66B	
Date Codes			Voltages
Y = Year	M = Month	WW = Work Week of Assembly	% = Minimum Voltage
3: 2013 7: 2017	A: January	02: Week 2	M: 1.7V min
4: 2014 8: 2018	B: February	04: Week 4	
5: 2015 9: 2019	
6: 2016 0: 2020	L: December	52: Week 52	
Country of Assembly		Lot Number	Grade/Lead Finish Material
@ = Country of Assembly		AAA...A = Atmel Wafer Lot Number	U: Industrial/Matte Tin/SnAgCu H: Industrial/NiPdAu
Trace Code			Atmel Truncation
XX = Trace Code (Atmel Lot Numbers Correspond to Code) Example: AA, AB.... YZ, ZZ			AT: Atmel ATM: Atmel ATML: Atmel

3/22/13

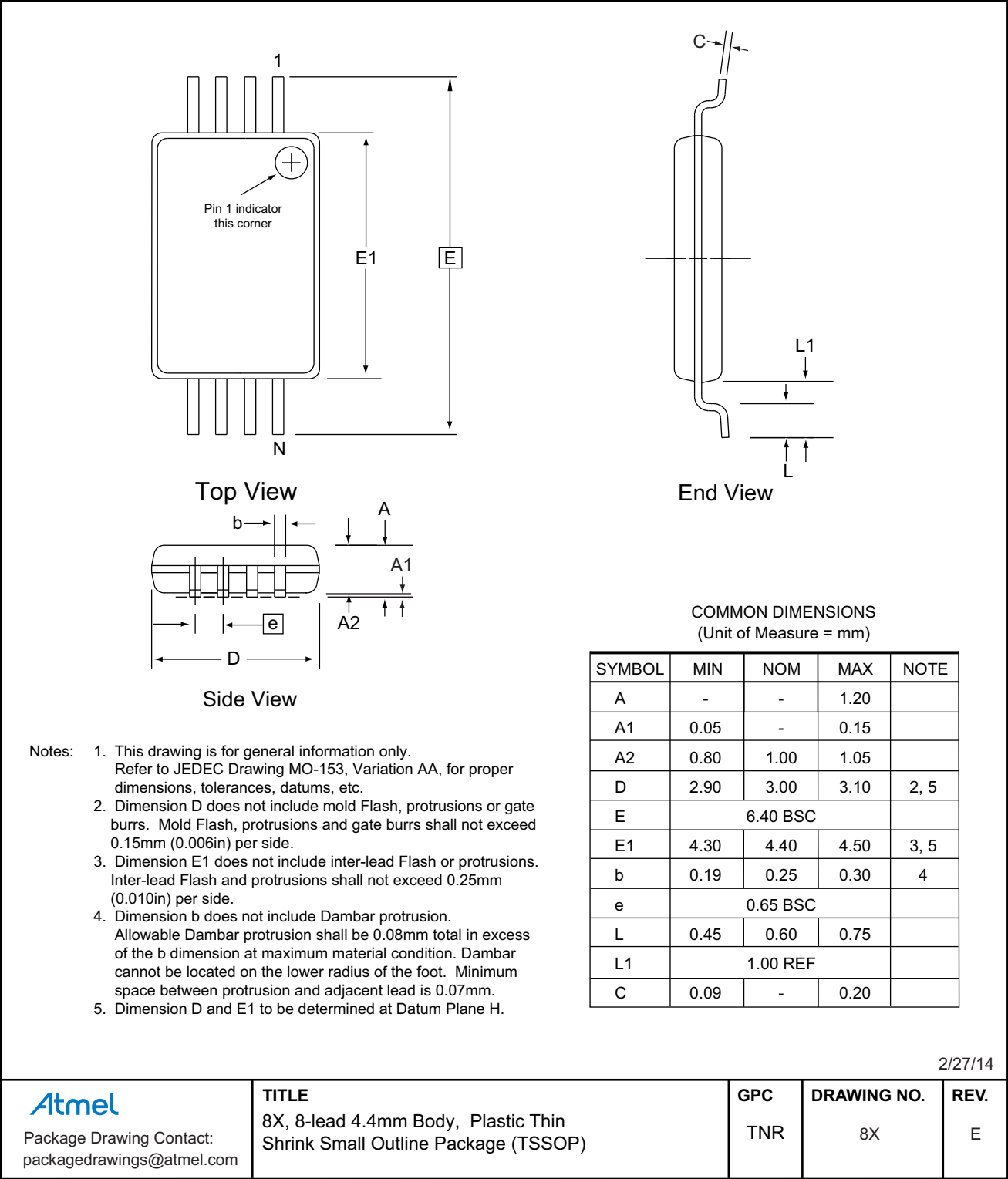
 Package Mark Contact: DL-CSO-Assy_eng@atmel.com	TITLE 93C56-66BSM , AT93C56B and AT93C66B Package Marking Information	DRAWING NO. 93C56-66BSM	REV. B
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10. Packaging Information

10.1 8S1 — 8-lead JEDEC SOIC



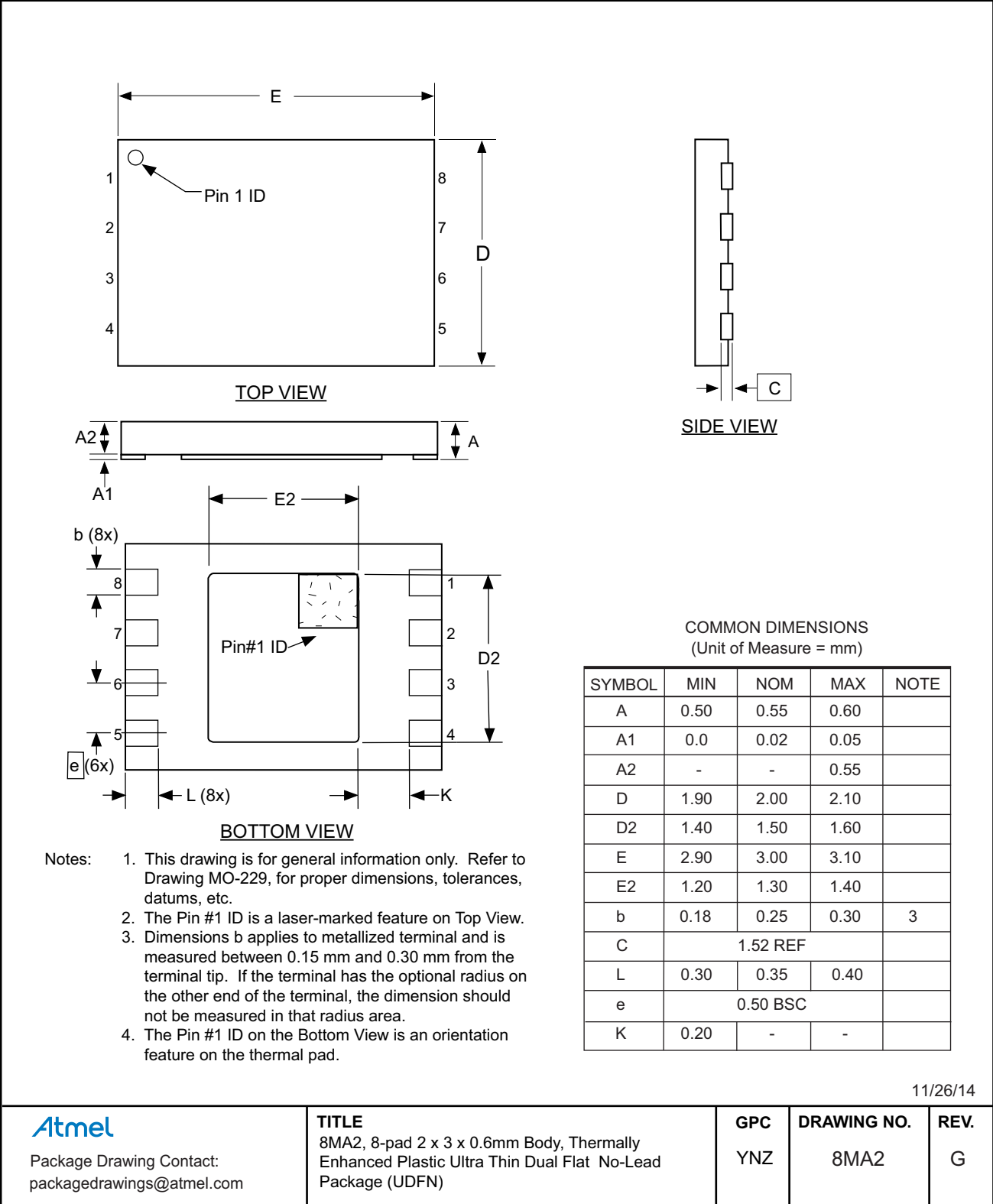
10.2 8X — 8-lead TSSOP



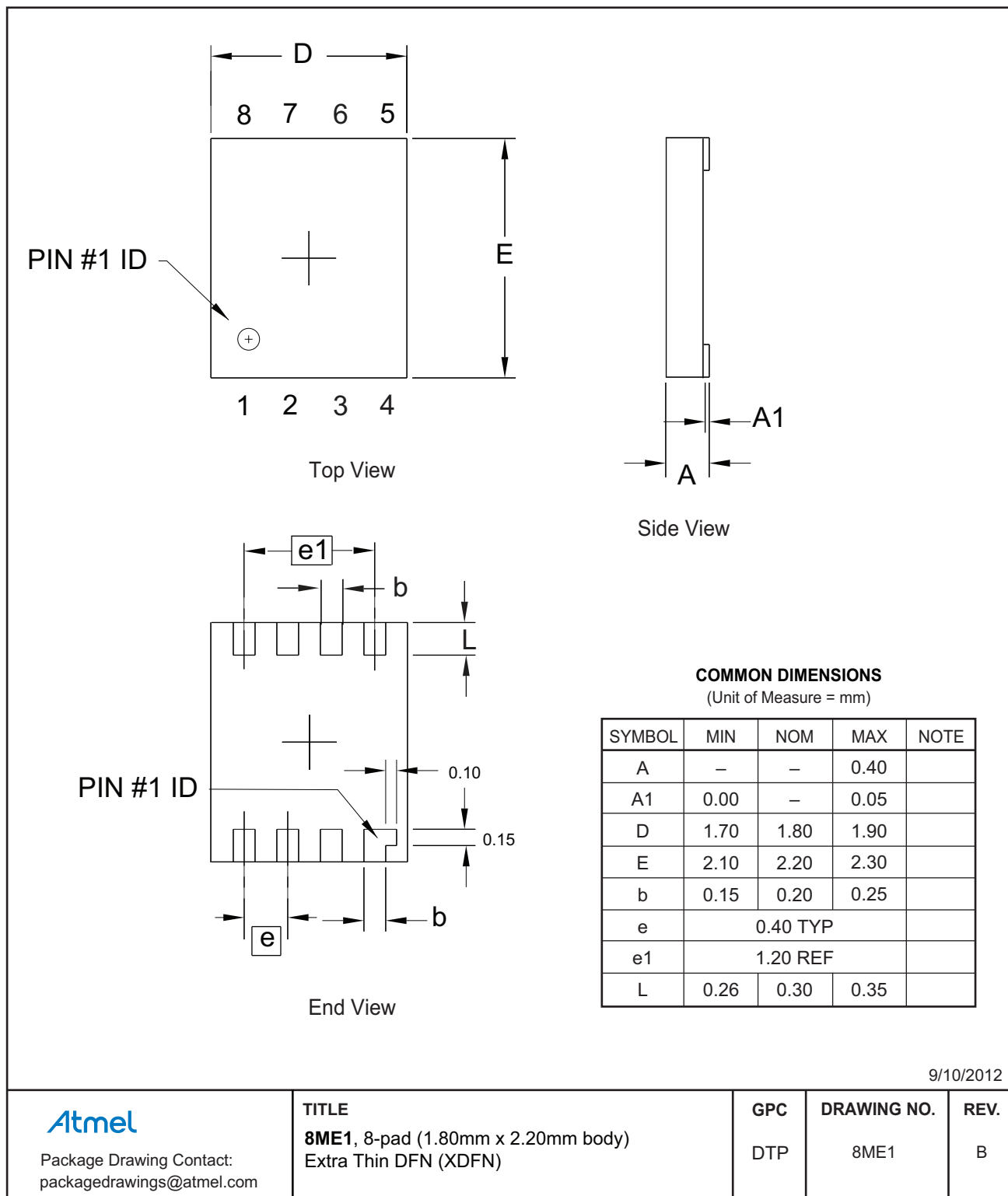
2/27/14

 Package Drawing Contact: packagedrawings@atmel.com	TITLE 8X, 8-lead 4.4mm Body, Plastic Thin Shrink Small Outline Package (TSSOP)	GPC TNR	DRAWING NO. 8X	REV. E
---	---	-------------------	--------------------------	------------------

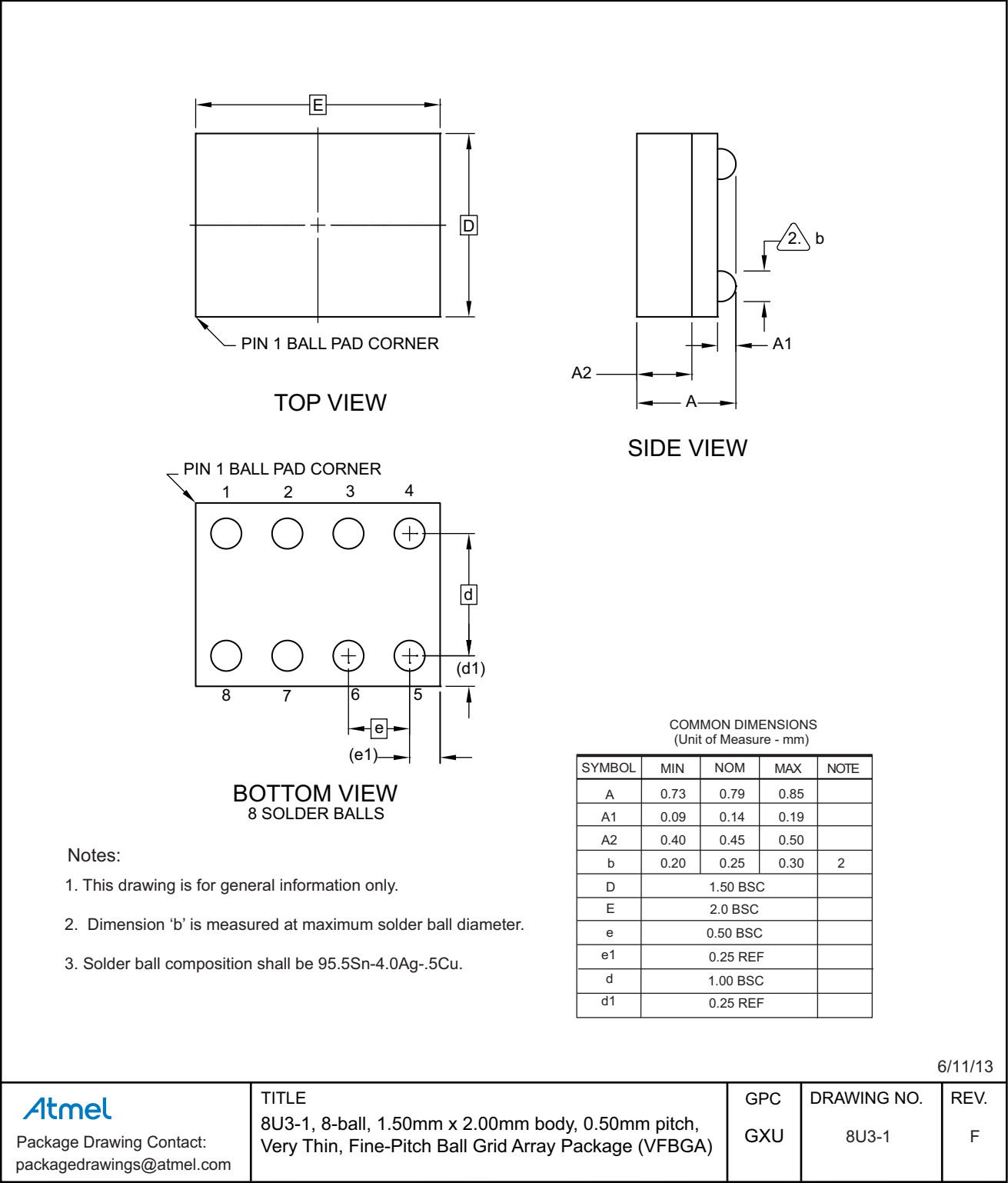
10.3 8MA2 — 8-pad UDFN



10.4 8ME1 — 8-pad XDFN



10.5 8U3-1 — 8-ball VFBGA



6/11/13

 Package Drawing Contact: packagedrawings@atmel.com	TITLE 8U3-1, 8-ball, 1.50mm x 2.00mm body, 0.50mm pitch, Very Thin, Fine-Pitch Ball Grid Array Package (VFBGA)	GPC GXU	DRAWING NO. 8U3-1	REV. F
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11. Revision History

Rev. No.	Date	Comments
8735C	01/2015	Add the UDFN extended quantity option and update package outline drawings. Update the 8MA2 package drawing.
8735B	04/2013	Correct Synchronous Data Timing figure and remove note. Update TSSOP package option from 8A2 to 8X. Update UDFN package option from 8Y6 to 8MA2. Update template and Atmel logos.
8735A	01/2011	Initial document release.



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